NSN 5961-01-338-1286

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View Online at https://aerobasegroup.com/nsn/5961-01-338-1286 **Inclosure Material:** Ceramic or plastic **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Electrostatic sensitive Voltage Rating In Volts Per Characteristic: 60.0 drain to gate voltage all transistor and 60.0 drain to source voltage all transistor and 4.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 0.23 amperes drain current all transistor and 1.00 amperes off-state current, peak all transistor **Power Rating Per Characteristic:** 2.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli